



University
of Glasgow

Amorphous Coatings for Future Detectors

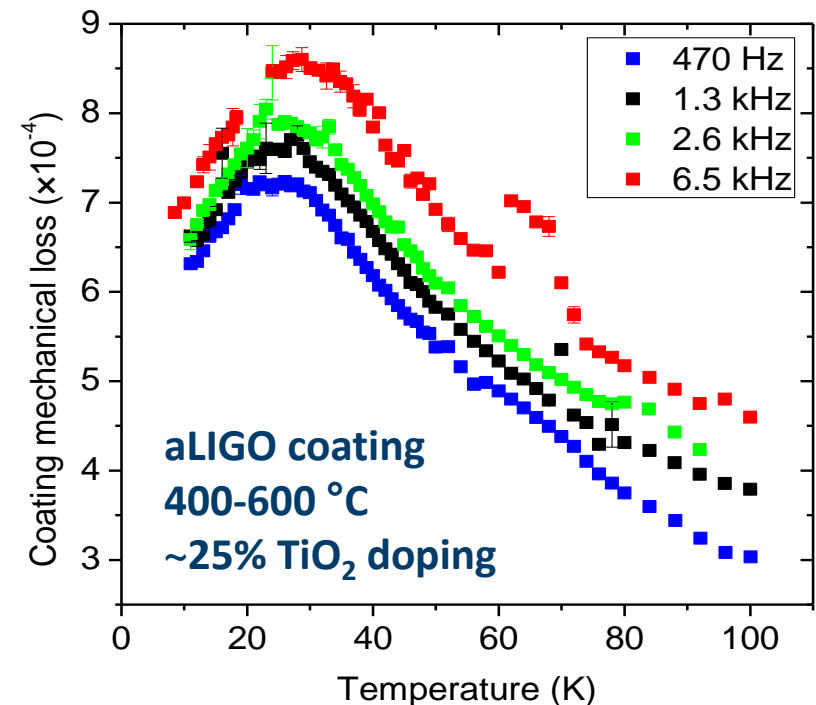
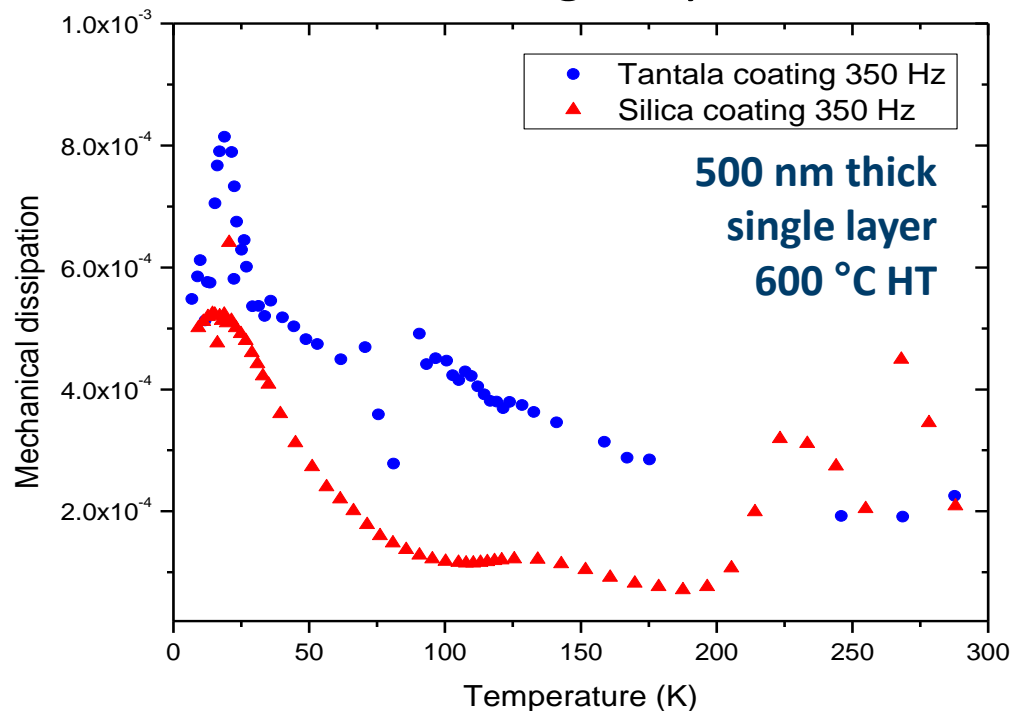
Dr. Peter G. Murray et al.

Institute for Gravitational Research
SUPA, University of Glasgow



Coatings Workshop, Lyon, 20/11/14

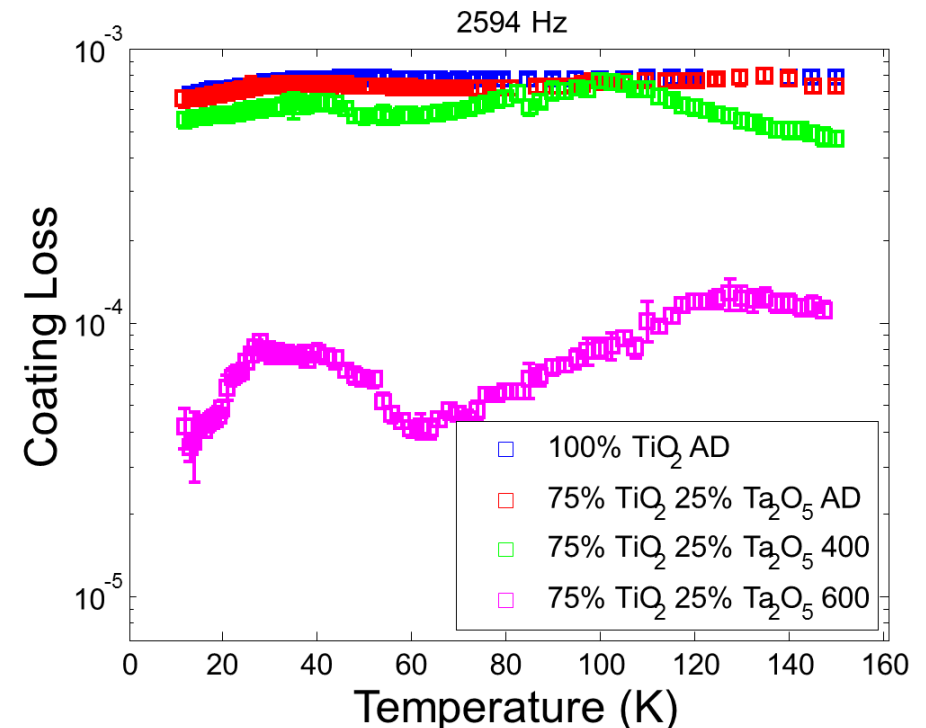
- Cryogenic loss peaks in tantala / silica films suggest a reduction in coating thermal noise by $\sim 2\times$ by cooling to 20 K
- Observed on both single layers^{1,2} and aLIGO coating³



- Peaks at higher temperature (~ 30 K) in multilayer coatings (aLIGO)
- No strong peak in SiO₂/Ta₂O₅ on sapphire measured at ICRR⁴

¹Martin et al., CQG (2014), ²Martin et al., CQG (2010), ³Granta et al., Opt. Lett. 38 (2013), ⁴E. Hirose et al., PRD (2014)

- **Why is the loss of silica so much lower, at room temperature, than other oxide materials?**
- **What is the origin of the cryogenic loss peaks in tantalum?**
- Starting to get some evidence to disentangle doping and heat-treatment and correlate with structural data
- **600 °C heat treated
75% TiO₂/Ta₂O₅ coating**
- large reduction in loss
- plus evidence of crystallisation
- However, interesting to obtain such a low loss from this material system
- Studying onset of low loss (500 °C HT)



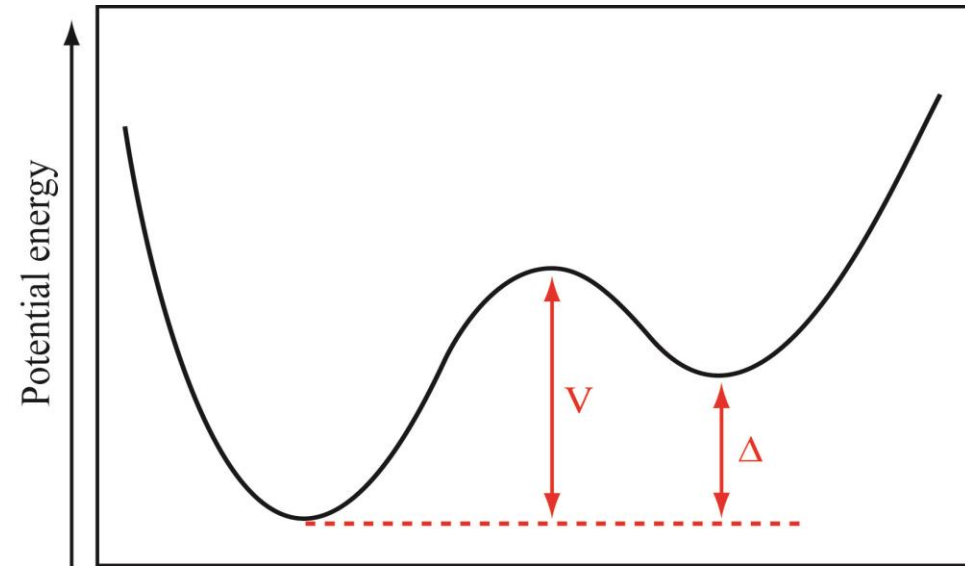
- **Various high-index materials are showing some promise: $\text{SiO}_2\text{:HfO}_2$, aSi, work on silicon nitride and nano-layering by Chao, Pinto et al.**
- **To maximise improvement in TN from any of these materials, require more work on low-index layers**
- Understand cryogenic loss of IBS silica
- Possible alternative materials?
- **Little improvements (discussed at Stanford workshop)**
- Rather than looking for a magic bullet, can we find lots of incremental improvements which add up to a significant TN reduction?
 - i.e. UK Cycling “Marginal Gains”
- e.g. multi-material coatings to exploit low loss of aSi
- Other optimisations?



- **Amorphous structure results in distribution of potential barrier heights $g(V)$**
- Activation energy calculated from Arrhenius law corresponds to the average barrier height in this distribution
- The barrier height distribution function $g(V)$ can be calculated from temperature dependent loss data

$$\phi = \frac{\pi\gamma^2 f_0}{C_{ii}} k_B T g(V)$$

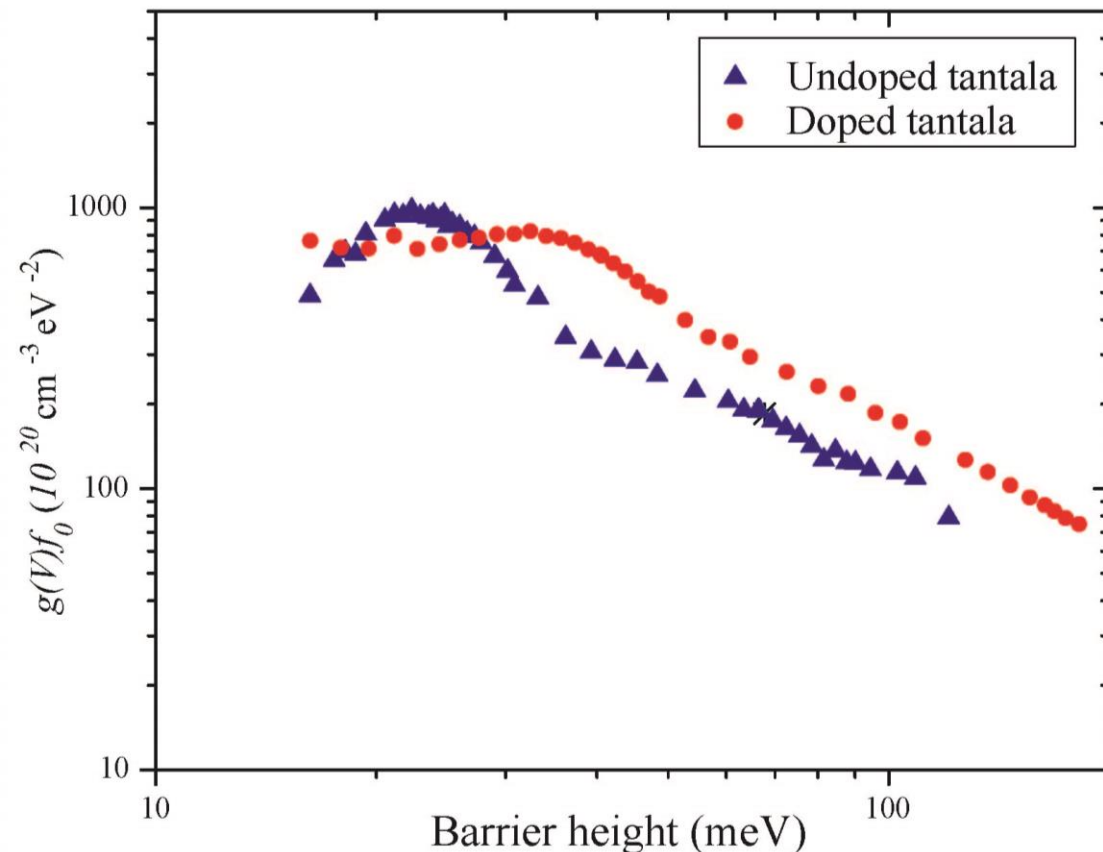
C_{ii} is the elastic constant of the material



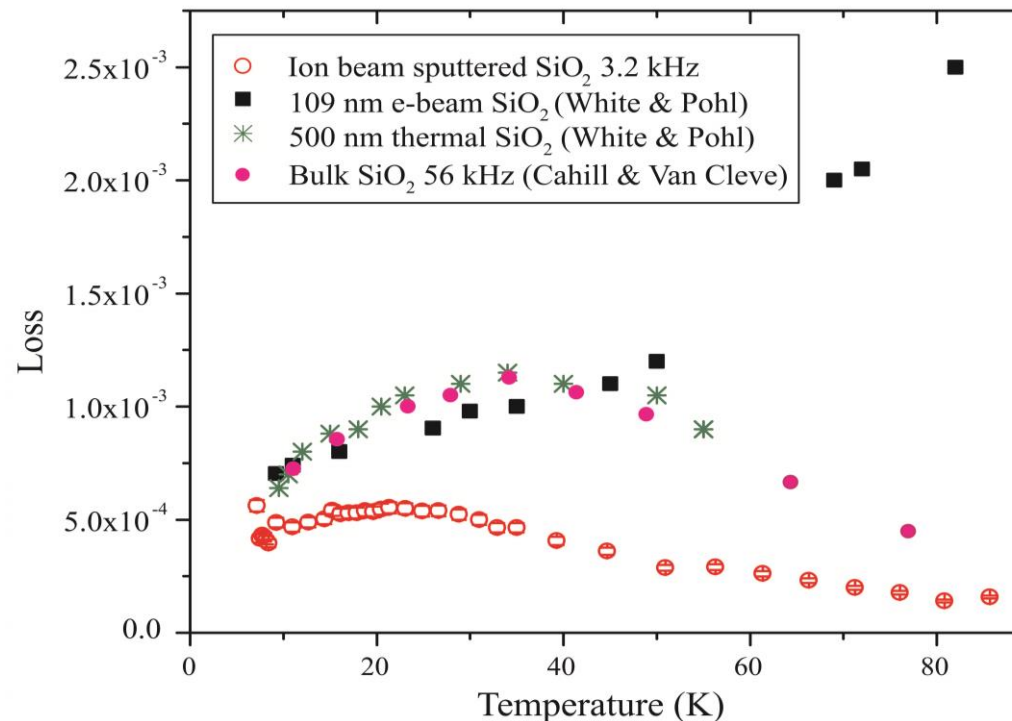
γ represents the coupling between strain and the dissipation mechanism

- Activation energy and time constant of process responsible for loss

- **Barrier height distribution function can be calculated from cryogenic loss**
- **TiO₂ doping shifts distribution to a higher energy, increases width of distribution**
- Thus reducing loss
- **Other methods of altering distribution**
- Perhaps heat treatment?
- **Structural work**
- Understand amorphous structure and loss mechanisms



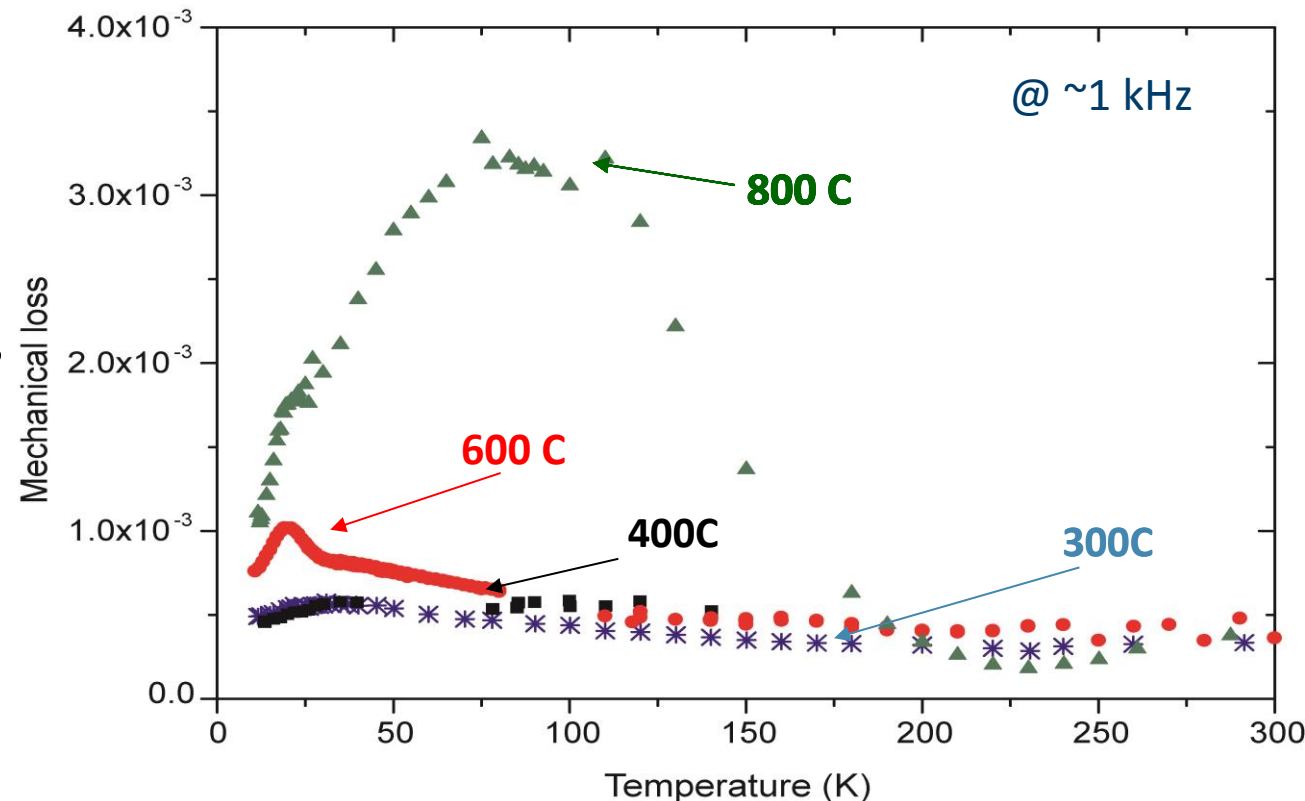
- **Loss of silica very dependent on deposition method**
- Thermally grown SiO_2 on Si is very similar to bulk SiO_2
- Whereas IBS SiO_2 performs worse than bulk (3.2 kHz plotted here)



- **Structural differences/ deposition method are clearly really important**
- Could stress be a factor too?

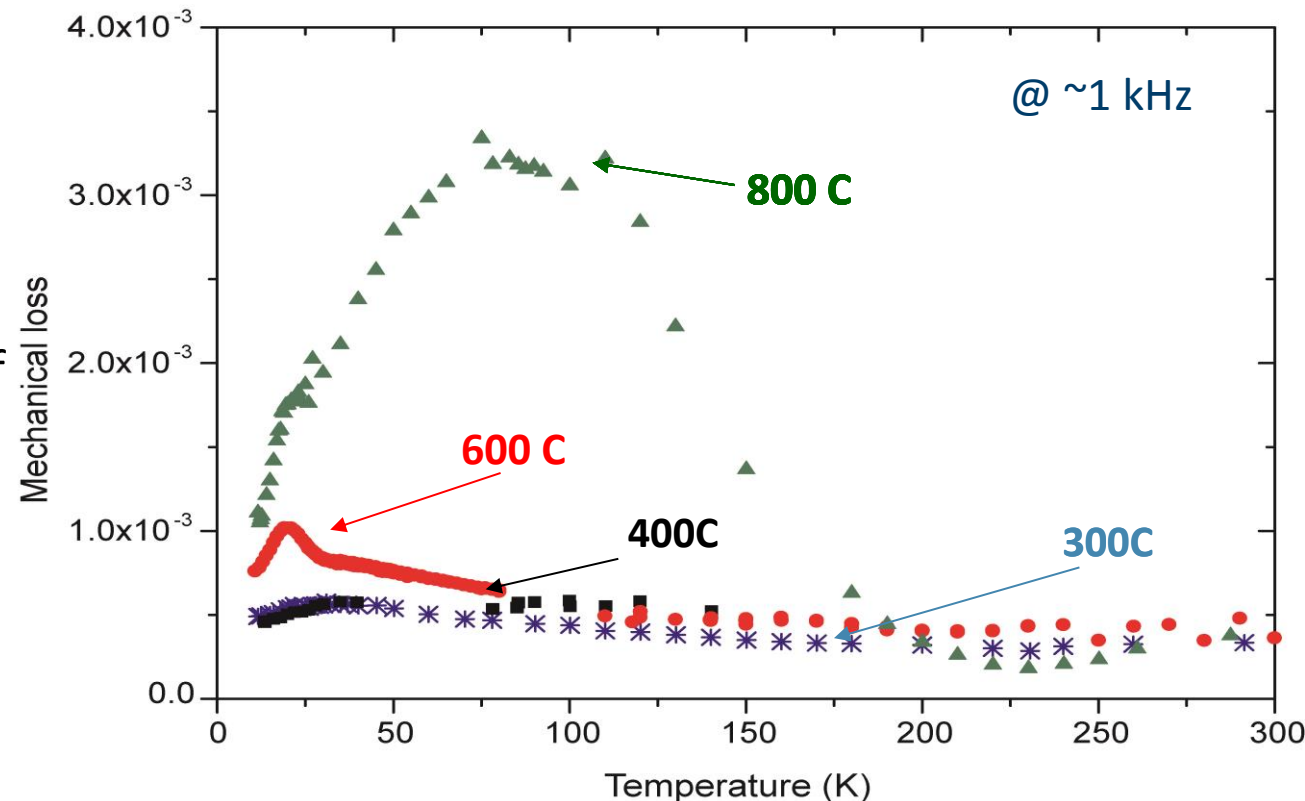


- **Effect of heat-treatment on mechanical loss and atomic structure of tantalum films**
- Investigated un-doped tantalum and different percentage dopings with titania
- **Found that heat treatment can significantly alter the temperature dependence of mechanical loss**
- True of both un-doped tantalum films and TiO₂-doped tantalum films
- **The emergence of mechanical loss peaks after heat treatment of particular interest**

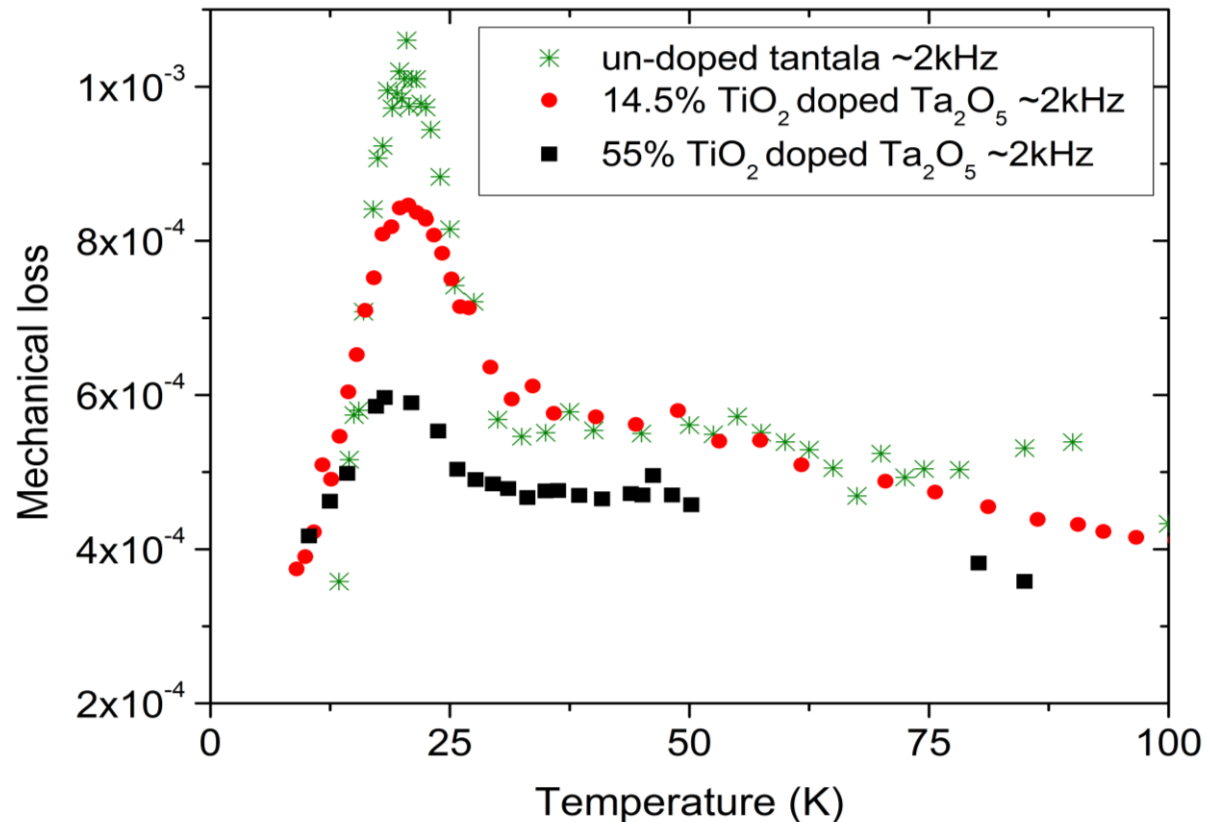




- Higher heat-treatments result in low-temperature loss peaks
- Three mechanical loss peaks identified in tantalum films:
 - Low, broad peak ~ 35 K after both 300°C and 400°C Heat Treatment
 - Also present in as-deposited tantalum
 - Sharper peak at ~ 20 K following 600°C HT
 - Large, broad peak ~ 90 K following 800°C HT
- Thought to be associated with the crystallisation of the coating at this heat treatment temperature



- Studied the effect of heat treatment on the cryogenic mechanical loss of Ta_2O_5 films doped with various concentrations of TiO_2
- Results indicate, for 600 °C HT, increasing the concentration of titania doping tends to suppress cryogenic loss

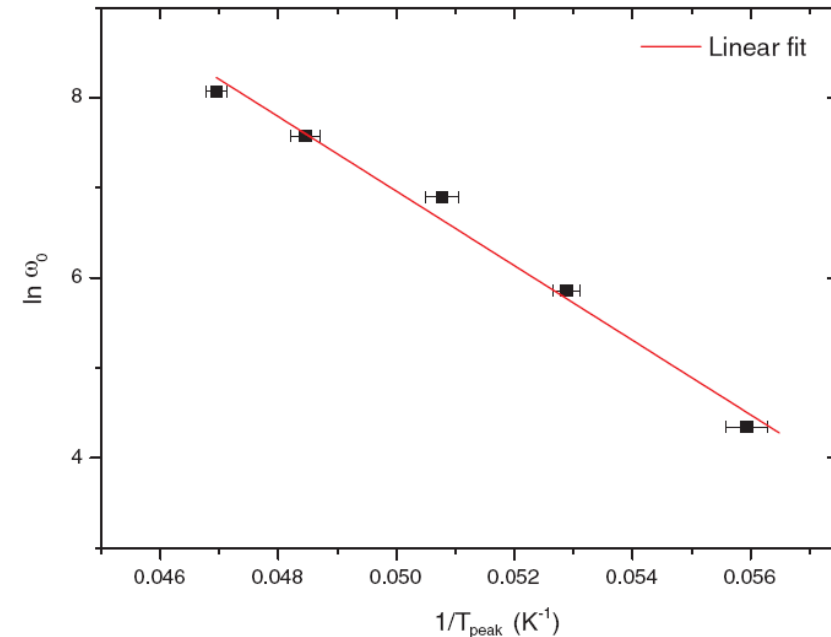
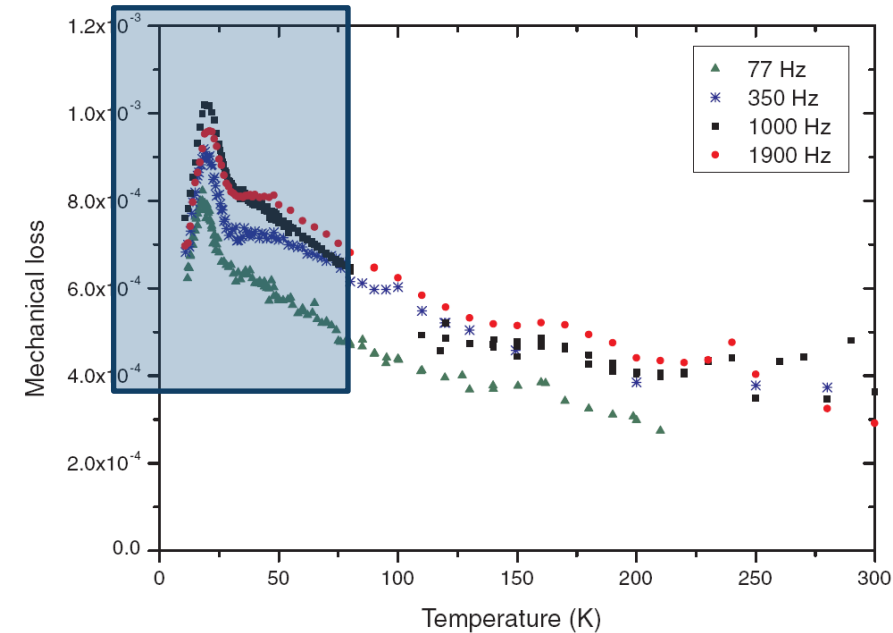


- **TiO₂-Ta₂O₅ – optimisation of heat-treatment**
- Doping may allow losses similar to room-temperature to be achieved

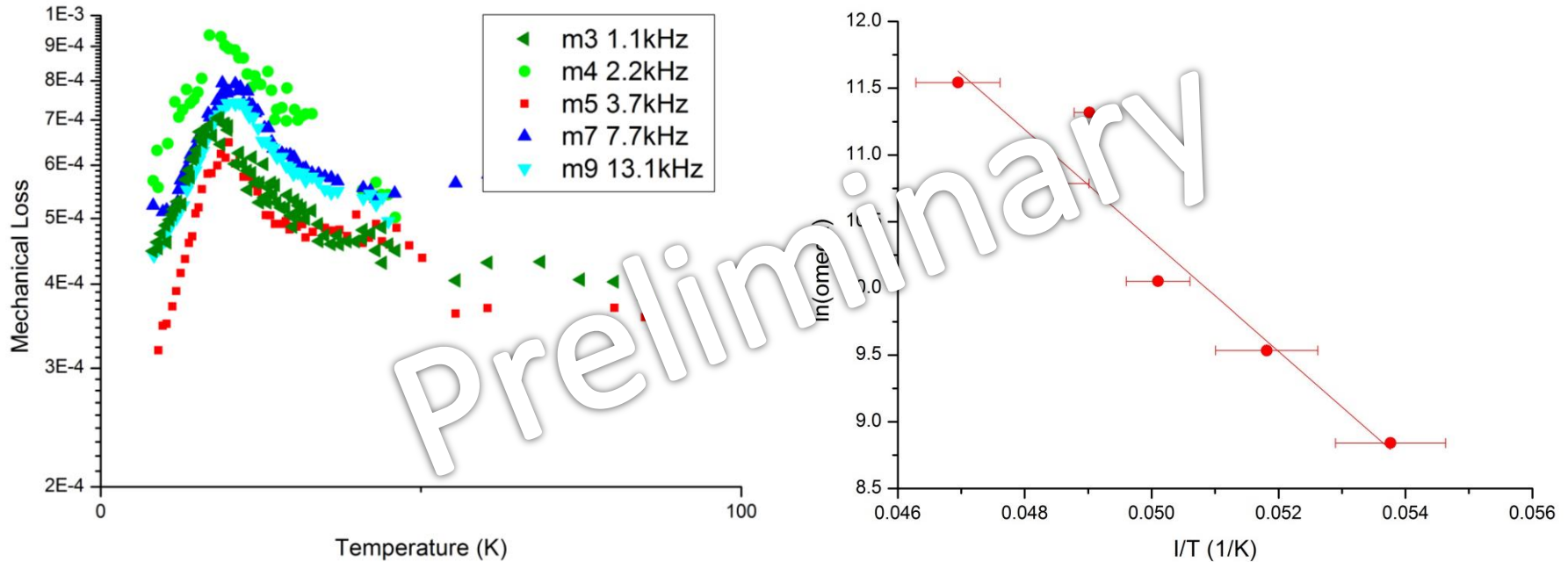
- **Effect on optical absorption?**

- **Multilayer coating loss?**
- Loss peak in silica layers
- Similar reduction in loss of silica required

- Ta_2O_5 coating heat treated at $600\text{ }^\circ\text{C}$
- The temperature at which the dissipation peak $\sim 20\text{ K}$ occurred was found to vary with frequency
- Typical characteristic of this thermally activated dissipation process
- The activation energy and rate constant are calculated from a linear fit to an Arrhenius plot
- $E_a = 35.6 \pm 2.5\text{ meV}$
- $\tau_0 = (9.9 \pm 0.5) \times 10^{-13}\text{ s}$

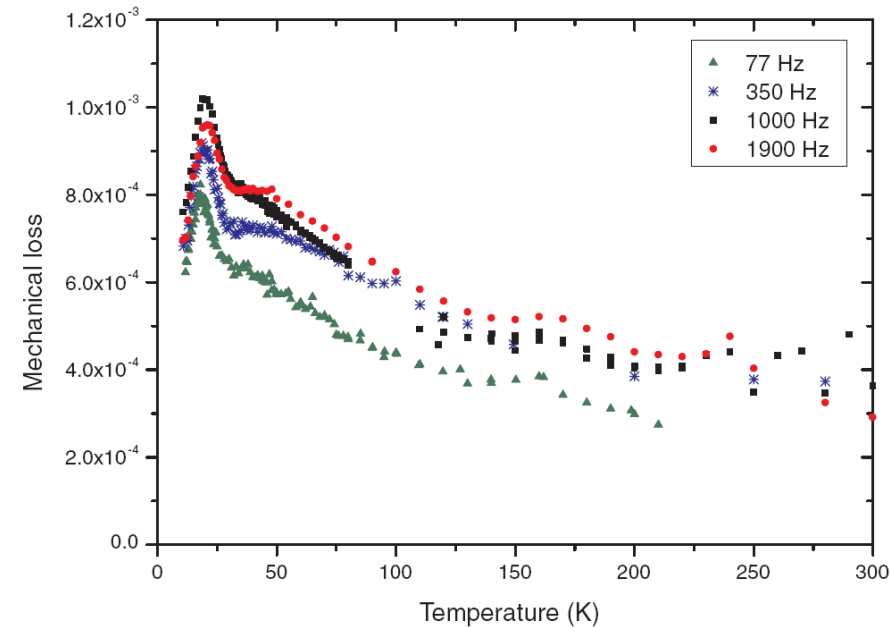


- Recently measured a 55%-TiO₂ doped Ta₂O₅ coating with a 600 °C HT

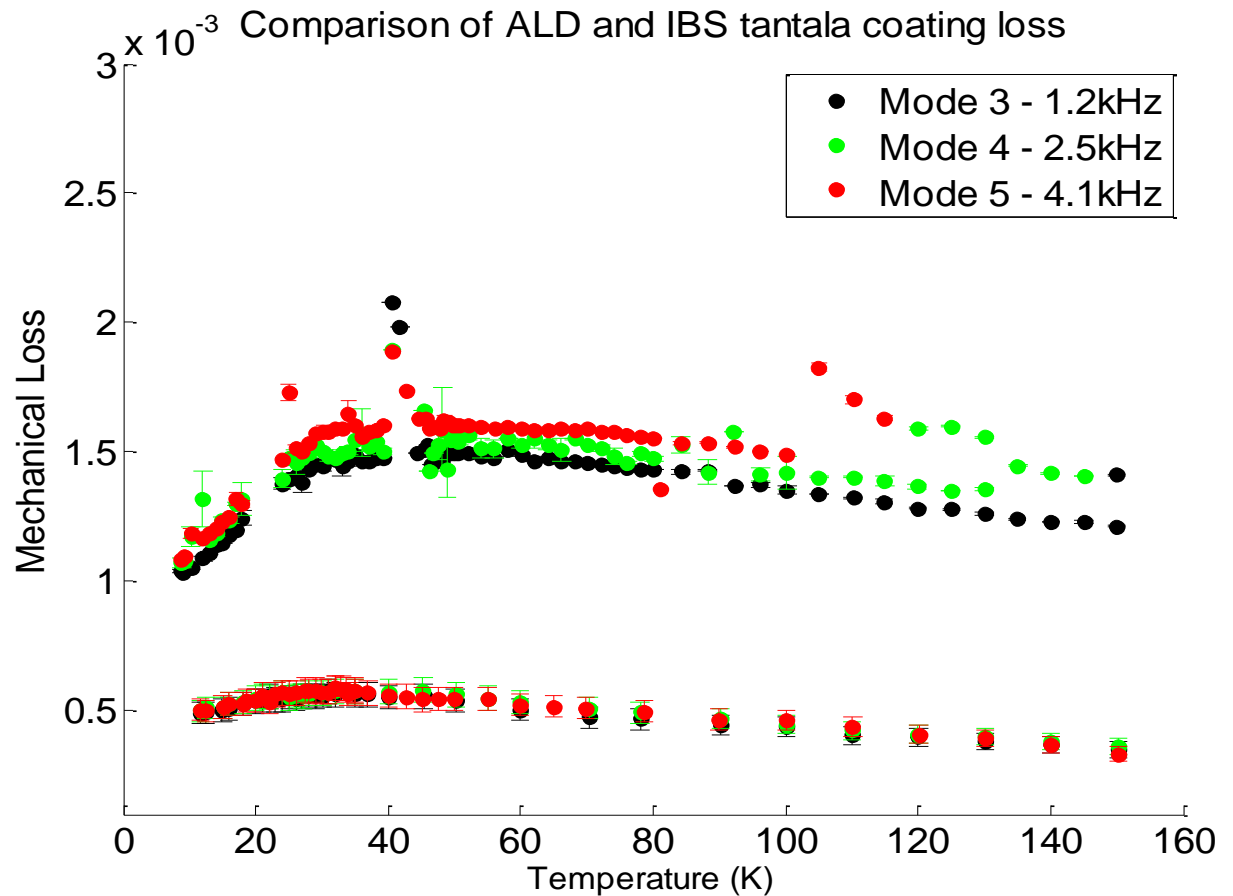


- Again the dissipation peak was observed to vary with frequency
- The activation energy and rate constant for this coating
- $E_a = 35 \pm 5$ meV
- $\tau_0 = (3 \pm 2) \times 10^{-14}$ s
- Suggests doping doesn't strongly influence the 20 K loss peak

- Looking back again at Ta_2O_5 coating heat treated at 600 °C
- The tail of the 20 K peak is not responsible for room temperature loss
- However, the tail of an underlying 35 K peak could be
- Perhaps the 20 K peak is largely a function of heat treatment
- The 35 K peak could actually be more strongly affected by doping
- This possibly accounts for:
 - The differences in room temperature loss with doping
 - For the suppression of the cryogenic loss with doping

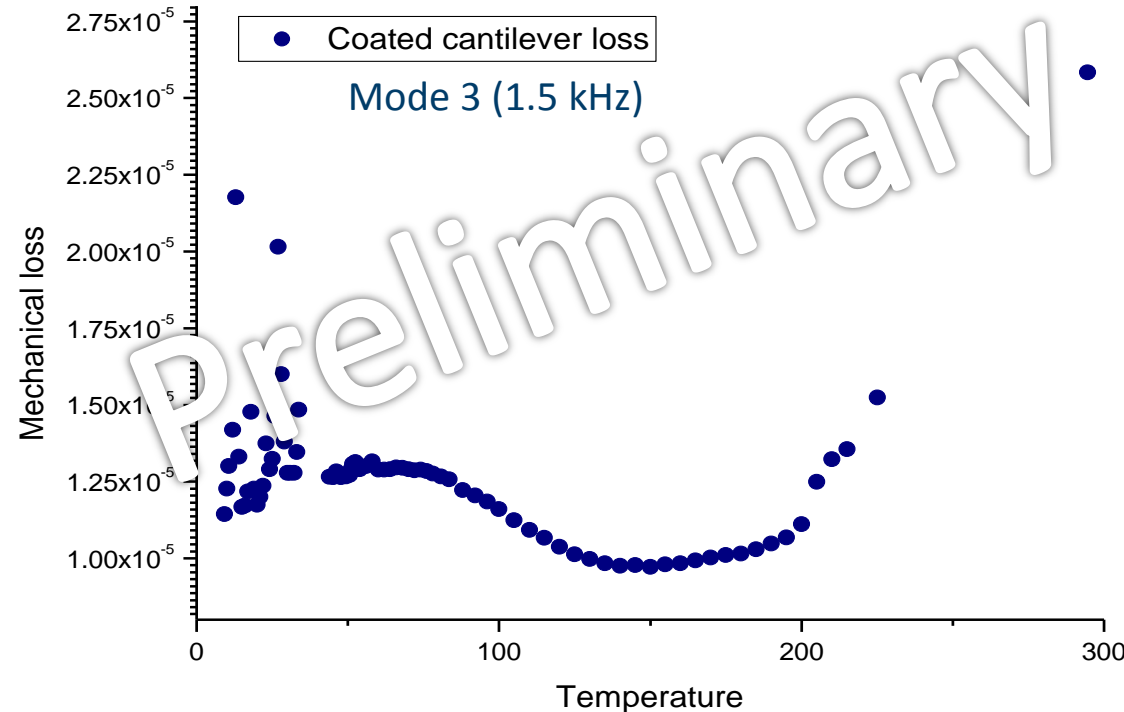


- Of interest to compare different deposition methods
- ALD tantalum dissipation measured on silicon cantilevers
- ALD compared to IBS tantalum heat treated at 300°C
- Structural studies underway
- Note: ALD loss shown assumes no loss in the substrate under 150 K and is therefore only an upper limit

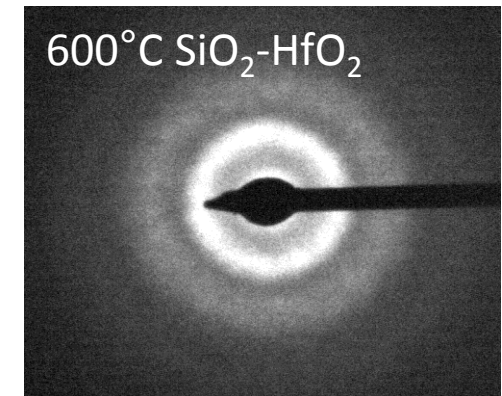
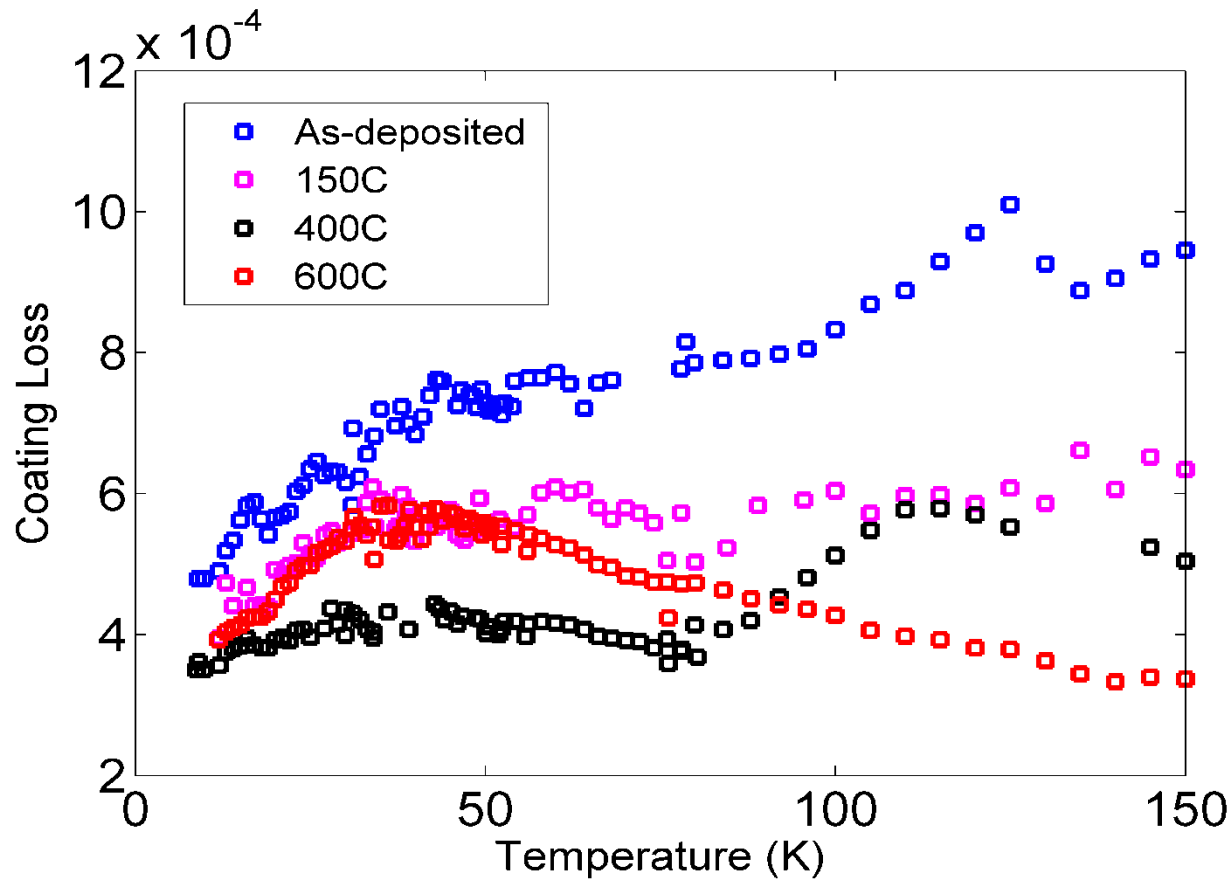




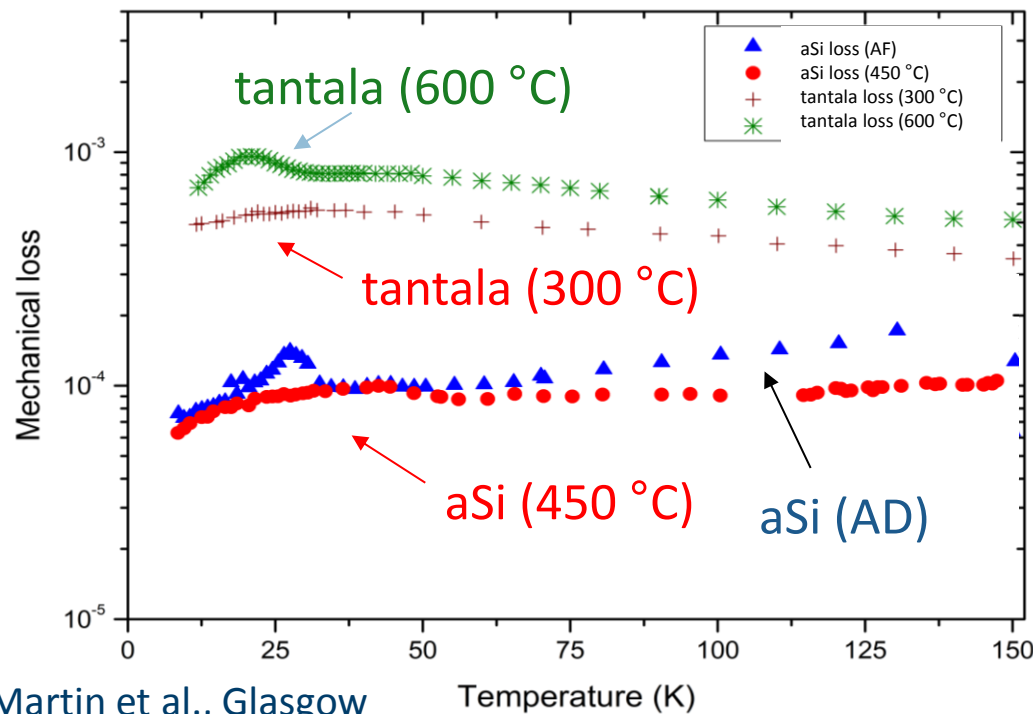
- **Investigating zirconia as a coating material**
- doped with silica to stabilize it and allow higher annealing temperature without crystallisation
- **Also as a dopant for other materials**
- E.g. in tantala testing modelling prediction that it should give structures with a similar flexibility to titania doping
- **Multilayer coating:**
 - zirconia/silica/zirconia/silica
 - Quarter wavelength at 1064nm
 - **Other modes need more data taken – too much scatter**
 - **Coated cantilever loss (i.e. not pure coating loss) shown**



- **30% silica-doped hafnia (CSIRO, 500 nm, Si cantilevers)**
- Silica prevents crystallisation, heat-treatment up to 400 °C reduces loss
- Best amorphous oxide coating so far (almost) no low temperature loss peak
- Heat-treatment also reduces optical absorption

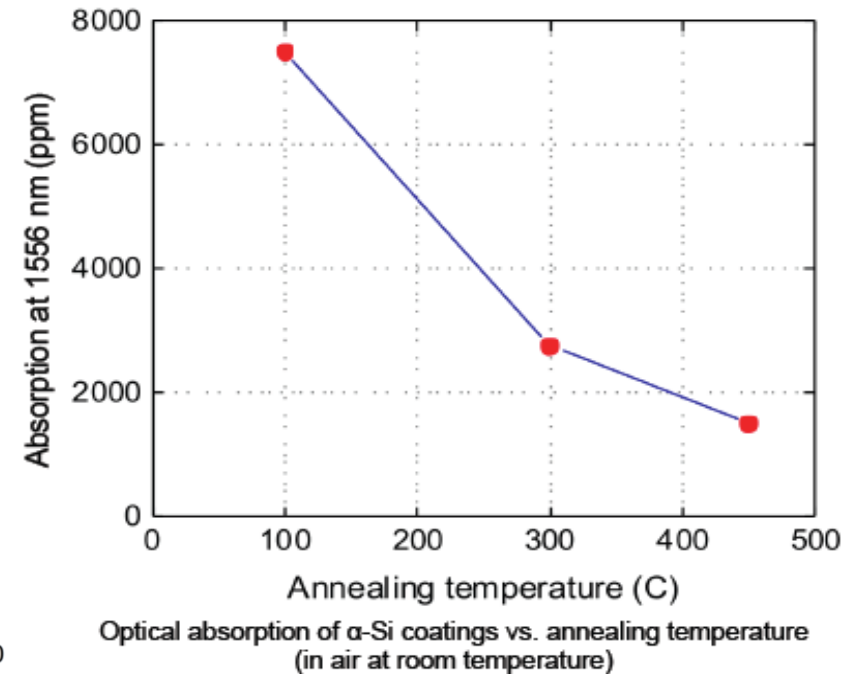


- **1550nm required**
- **Low mechanical loss**
- Mechanical loss of 0.5 μm IBS amorphous silicon is approximately a factor of ten lower than tantala below 100 K
- **So far, optical absorption significantly too high**
- still ~ 1000 ppm after HT



I. Martin et al., Glasgow

Temperature (K)



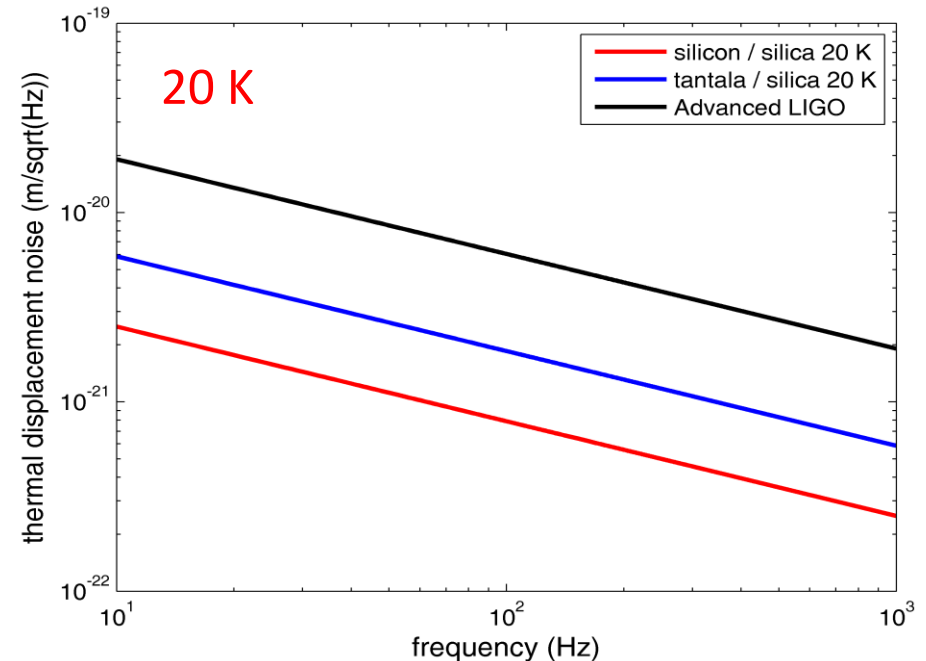
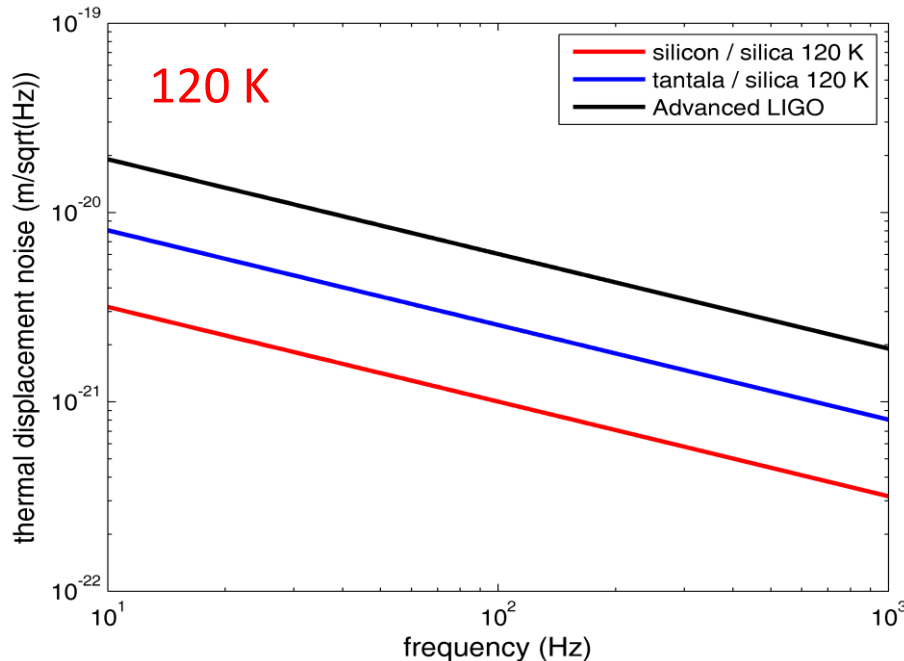
Stanford - A. Markosyan, R. Bassiri et al.

- **Si/SiO₂ requires only 6 doublets**
- For equivalent reflectivity as 15 doublets of Ta₂O₅/SiO₂
- **Saw loss of Si << Ta₂O₅ at cryogenic temperatures**
- Coating loss limited by cryogenic loss of silica layers

Thermal noise reduction in comparison to Advanced LIGO design*

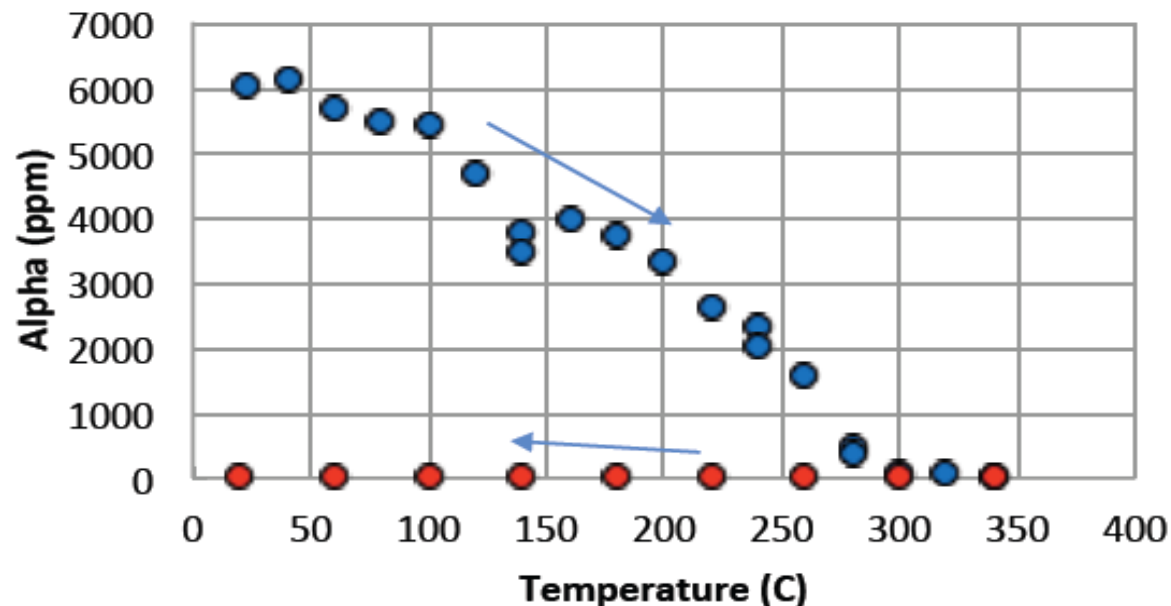
	120 K	20 K
Ta ₂ O ₅ /SiO ₂	2.3	3.2
Si/SiO ₂	6.0	7.6

Assuming beam radius 9.95 cm (Strawman Red)



* $\lambda=1064$ nm, $T=300$ K, beam rad.= 6.2 cm

- **As seen with silica doped hafnia, heat-treatment can reduce absorption**
- **Hydrogenation?**
- Terminating dangling bonds can reduce mechanical loss
- Studies at Stanford and Glasgow
- **Interesting to note:**
Large reductions in absorption can be achieved in some materials
- e.g. Ashot's talk at Stanford Coating Workshop on Al-ZnO
- absorption can be reduced from 6000ppm to 4.5ppm



- **A lot of progress towards improved high-index materials**
- **Need to consider low-index materials at low temperature**

- **Understanding loss, links between loss and structure, is important**
- see structural talks

- **Other methods of altering loss**
- Deposition parameters?
- Alternative materials?
- Alternative dopants – predicted by modelling/structural work?